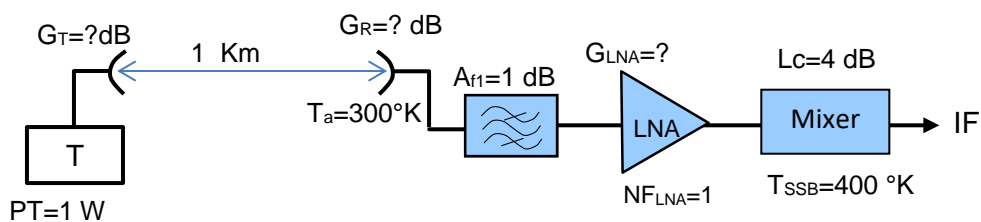


**RF SYSTEMS**  
**Written Test of July 24<sup>th</sup>, 2018**

<b>Surname &amp; Name</b>
<b>Identification Number</b>
<b>Signature</b>

Exercise 1

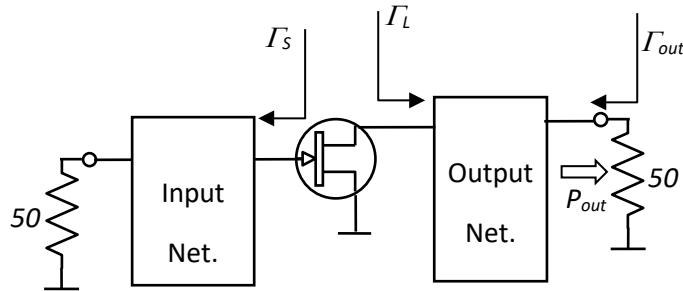


Consider the scheme in the figure, which refers to a point-to-point communication system operating at 60 GHz with a signal having  $B=1000$  MHz bandwidth (1024 QAM). All the relevant system parameters are reported in the scheme (except  $G_{LNA}$  and  $G_R=G_T$  to be assessed).

- 1) Evaluate the minimum gain of the antennas (imposed equal), assuming the received power  $P_R \geq -50$  dBm
- 2) Imposing the minimum data rate  $R$  of the system equal to 7.5 Gbit/s with  $E_b/N_0=22$  dB, evaluate the requested value of the system equivalent temperature ( $T_{sys}$ )
- 3) Evaluate  $G_{LNA}$  in order to get the requested  $T_{sys}$
- 4) If the LNA is removed, what is the new value of  $T_{SSB}$  for maintaining  $T_{sys}$  unchanged?

### Exercise 2

We want design a single stage amplifier at 12 GHz delivering  $P_L=20$  dBm to the load, using the scheme in the following figure (input and output networks are lossless):



The transistor has the following parameters:

$$S_{11}=0.57\angle 166^\circ \quad S_{21}=2.59\angle -21^\circ \quad S_{12}=0.144\angle -50^\circ \quad S_{22}=0.39\angle -148^\circ$$

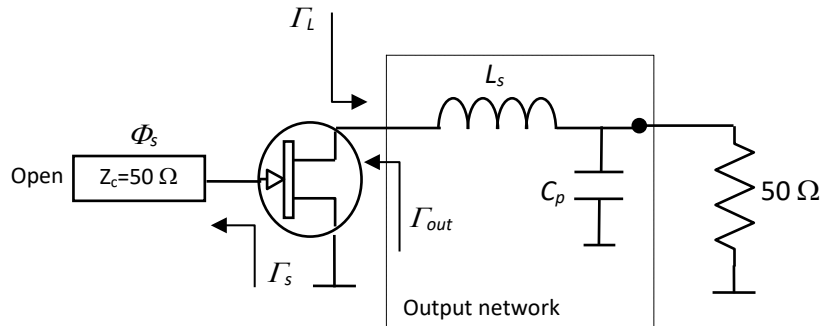
$$\Gamma_{opt}=0.435\angle 168^\circ \quad F_{min}=1.15 \text{ dB} \quad R_n=0.095 \text{ (Noise parameters)}$$

The amplifier must exhibit the noise figure as small as possible, compatibly with the stability requirement and with the Transducer Gain not lower than 11 dB.

- 1) Select a proper value for  $\Gamma_s$  and  $\Gamma_L$  in order to satisfy the above requirements
- 2) Select for the output network the topology you prefer and evaluate all the components.
- 3) Assume the signal constituted by 2-tone at 11.99 and 12.01 GHz with  $P_L$  (20 dBm) average power on the load. Determine the requested value of the 3<sup>th</sup> order Intercept point (IP3) in order CI (carrier-to-intermodulation ratio) at the output is equal to 30 dB. Compute also the power at each intermodulation frequency (specify the value of these frequencies)

### Exercise 3

We want design the oscillator in the following figure, operating at 5 GHz:



The scattering parameters of the transistor are given by:

$$S_{11} = 0.844 \angle -62.3^\circ, S_{21} = 5.273 \angle 121.7^\circ, S_{12} = 0.069 \angle 42.7^\circ, S_{22} = 0.521 \angle -52.6^\circ$$

- Select a value for  $\Gamma_s$  and evaluate the electrical length  $\Phi_s$  of the first line. (Hint: set  $|\Gamma_{out}| = 1.2$  and select the  $\Gamma_s$  which determines the minimum value of  $\Phi_s$ )
- Design the output network, once the required value of  $\Gamma_L$  has been computed ( $L_s$  and  $C_p$  must be positive numbers)

Solutions

Ex.1

$$K = 1.38 \cdot 10^{-23} \quad L = 1000 \text{ m} \quad \lambda = 3 \cdot 10^8 / 60 \cdot 10^9 = 0.005 \text{ m}$$

$$G = G_T = G_R$$

$$1) \quad P_R = P_T - 20 \log_{10} \left( \frac{4\pi L}{\lambda} \right) + 2G$$

$$G = (-80 + 128 - 0) / 2 = 24 \text{ dB}$$

$$2) \quad \text{SNR} = \frac{P_R}{K T_{\text{sys}} \cdot B} = \frac{E_b}{N_0} \cdot \frac{R}{B} \Rightarrow$$

$$\Rightarrow T_{\text{sys}} = \frac{1}{K} \frac{P_R}{\frac{E_b}{N_0} \cdot R} = 609.62 \text{ }^\circ\text{K}$$

$$3) \quad T_{\text{sys}} = T_a + T_f + 2 T_{\text{LNA}} \cdot a_f + T_{\text{SSB}} \cdot \frac{a_f}{g_{\text{ena}}}$$

$$T_f = T_0 (10^{0.1} - 1) = 75.09$$

$$T_0 = 290^\circ \quad a_f = 10^{0.1} = 1.26$$

$$T_{\text{ena}} = T_0 (10^{0.1} - 1) = 75.09$$

$$n_f = 10^{0.1} = 1.26$$

$$g_{\text{ena}} = \frac{T_{\text{SSB}} \cdot a_f}{T_{\text{sys}} - T_a - T_f - 2 T_{\text{ena}} \cdot a_f} = 11.07 \text{ (10.7 dB)}$$

$$4) \quad T_{\text{sys}} = T_a + T_f + a_f \cdot T_{\text{SSB}}'$$

$$T_{\text{SSB}}' = \frac{T_{\text{sys}} - T_a - T_f}{a_f} = 186.29 \text{ }^\circ\text{K}$$

Ex. 2

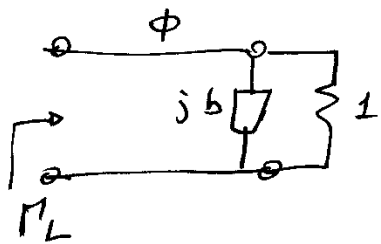
- 1) Assign  $G_{AV} = 11$ . Draw the circle  $G_{AV} = \text{const.}$  on the S.C. Draw few circles at  $M_F = \text{const.}$  ( $> 1.15$ ) - Find the circle tangent to the circle  $G_{AV} = \text{const.}$

The tangent point is  $M_S = 0.517 \angle -168.8$ .

Select "optimum  $M_L$ " to find  $M_L = 0.465 \angle -176$ .

The transistor is potentially unstable so it must be verified that  $M_S$  and  $M_L$  selected are outside the forbidden regions on the SC.

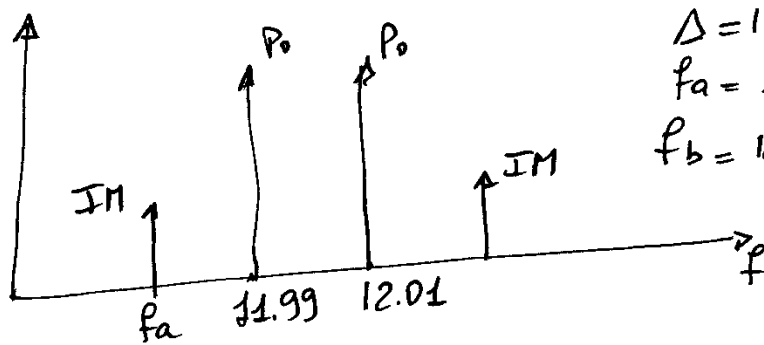
- 2) Design of a single stub network



$$\phi = \frac{58.6}{2} = 29.3$$

$$b = 1.045$$

- 3) Signal at amplifier output:



$$\Delta = 12.01 - 11.99 = 0.02$$

$$f_a = 11.99 - \Delta = 11.97$$

$$f_b = 12.01 + \Delta = 12.03$$

$$P_L = P_0 + 3 \Rightarrow P_0 = 14 \text{ dBm}$$

$$GI = 2IP_3 - 2P_L + 6 \Rightarrow IP_3 = \frac{70 - 6}{2} = 32 \text{ dBm}$$

$$IM = 3P_0 - 2IP_3 = 3 \cdot 14 - 64 = -13 \text{ dBm}$$

$$IM = P_0 - GI = 14 - 30 = -13 \text{ dBm}$$

Ex. 3

a) Draw the circle "Map Gamma Source" on the S.C.  
with  $|M_L| = 1.2$  - Select the intersection of  
this circle with the outer circle ( $|M| = 1$ ) which is  
closer to the open circuit (moving in the load  
direction) - We get  $M_S = 1 \angle 94.4^\circ$ .

Select "Gamma Out" :  $M_{out} = 1.2 \angle -47.6^\circ$   
 $Z_{out} = -0.535 - j2.16$

b) Assign  $Z_L = \frac{|R_{out}|}{3} - jX_{out} = 0.18 + j2.16$  to the  
current point - Draw the circle  $R = \text{const}$  passing  
for  $Z_L$  and the circle  $g = 1$  - There are two  
intersections between these circles, choose the one  
where the current value of  $b$  is positive :

$Y = 1 + j2.14$ . From "Delta Z" we have  
 $\Delta Z = 0 - j2.54$ , then  $X_S = 2.54 \cdot 50 = 127 \Omega$

$$L_S = \frac{X_S}{2\pi f_0} = 4.05 \mu\text{H}$$

$$B_p = \text{Im} \{Y\} \cdot 0.02 = 2.14 \cdot 0.02 = 4.28 \cdot 10^{-2}$$

$$C_p = \frac{B_p}{2\pi f_0} = 1.36 \text{ pF}$$